SHD120236

SENSITRON SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 4658, REV. A

HERMETIC SCHOTTKY RECTIFIER Low Forward Voltage Drop

Features:

- Soft Reverse Recovery at Low and High Temperature
- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	200	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle, rectangular wave form (Single)	15	A
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine wave (per leg)	200	A
Non-Repetitive Avalanche Energy	E_{AS}	$T_J = 25 \text{ °C}, I_{AS} = 3.0 \text{ A},$ L = 4.4 mH (per leg)	20	mJ
Repetitive Avalanche Current	I _{AR}	I_{AS} decay linearly to 0 in 1 µs f limited by T _J max V _A =1.5V _R	3.0	A
Maximum Thermal Resistance	$R_{ ext{ heta}JC}$	(Single)	1.21	°C/W
Max. Junction Temperature	ΤJ	-	-65 to +200	°C
Max. Storage Temperature	T _{stg}	-	-65 to +200	°C

Electrical Characteristics

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 15A, Pulse, T _J = 25 °C	1.01	V
(per leg)	V _{F2}	@ 15A, Pulse, T _J = 125 °C	0.85	V
Max. Reverse Current	I _{R1}	@V _R = 200V, Pulse,	0.1	mA
		T _J = 25 °C		
(per leg)	I _{R2}	@V _R = 200V, Pulse,	1.0	mA
		T _J = 125 °C		
Max. Junction Capacitance	CT	@V _R = 5V, T _C = 25 °C	300	pF
(per leg)		f _{SIG} = 1MHz,		
		$V_{SIG} = 50 mV (p-p)$		

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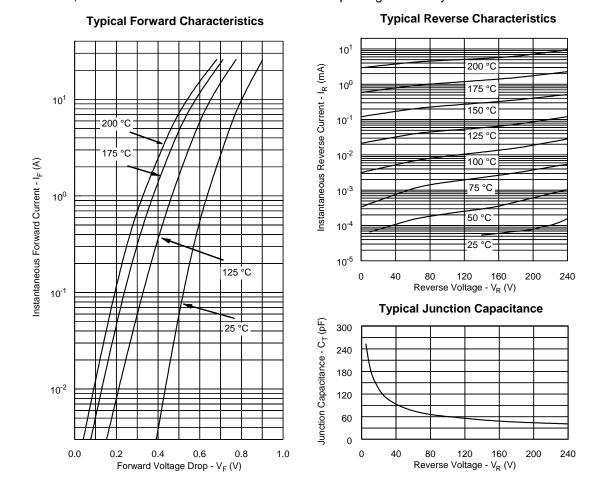
SINGLE RECTIFIER

LCC-5 Mechanical Dimensions: in Inches / mm SINGLE 0.100 2.54 (2 PLCS.) 0.301 - 0.291 7.39 0.122 - 0.112 2.84 - 0.030[0.76] MIN. 0.005 0.13 0.125 3.17 0.115 2.92 (2 PLCS.) 3 2 .030{.76[MIN. 2 3 1 0.406 10.31 1 0.230 5.84 0.220 5.59 R0.020[R0.51] 0.291 7.39 0.015 0.38 **PINOUT TABLE DEVICE TYPE** PIN 3 PIN 1 PIN 2

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Note: The V_f curves shown are for the SD125SCU200 unpackaged die only.

CATHODE



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